

PATENT  
81880.0087

30/ECT  
10/24/02  
A.Wall

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Hiroyuki KINOSHITA et al.

Serial No: 08/808,315

Filed: February 28, 1997

For: SAPPHIRE SINGLE CRYSTAL,  
SEMICONDUCTOR LASER  
DIODE USING THE SAME FOR  
SUBSTRATE, AND METHOD  
FOR MANUFACTURING THE  
SAME (Amended)

Art Unit: 2828

Examiner: James A. Menefee

I hereby certify that this correspondence  
is being transmitted via facsimile to (703-  
872-9318), Group 2828, Commissioner  
for Patents, Washington D.C. 20231, on

October 18, 2002

Date of Deposit

Diane Zynn

Name

Signature

10/18/02  
Date

PETITION FOR EXTENSION OF TIME

Commissioner for Patents  
Washington, D.C. 20231

FAX COPY RECEIVED

OCT 18 2002

Dear Sir:

TECHNOLOGY CENTER 2800  
In accordance with 37 C.F.R. 1.136, Applicant respectfully petitions the  
Commissioner for a one-month extension of time extending to October 19, 2002, the  
period for response to the Office Action dated June 19, 2002. Please charge the fee  
of \$110 for this extension to Deposit Account No. 50-1314. The responsive paper(s)  
are attached.

Please charge any insufficiency or credit any overpayment to Deposit Account  
No. 50-1314. A copy of this petition is enclosed.

Respectfully submitted,

HOGAN & HARTSON L.L.P.

By:

Brian D. Martin

Registration No. 47,771

Attorney for Applicant(s)

Date: October 18, 2002

11/06/2002 DEVANS 00000005 501314 08808315

01 FC:1251

110.00 CH

500 South Grand Avenue, Suite 1900  
Los Angeles, California 90071  
Phone: 213-337-6700  
Fax: 213-337-6701